NSN 5961-01-185-9481

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-185-9481 **Inclosure Material:** Metal **Overall Length:** 0.800 inches **Overall Height:** 0.210 inches **Overall Width:** 0.285 inches **End Application:** Radar system an/fps-117 **Internal Configuration:** Junction contact **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 32.0 collector-to-emitter, resistance between base and emitter and 3.5 emitter to base voltage, static, collector open **Power Rating Per Characteristic:** 4.3 watts small-signal input power, common-collector absolute **Transfer Ratio:** 120.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** External surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 2 flange and 2 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

Fiig:

A110a0